MJ11015 (PNP); MJ11012, MJ11016 (NPN)

MJ11016 is a Preferred Device

High-Current Complementary Silicon Transistors

... for use as output devices in complementary general purpose amplifier applications.

- High DC Current Gain –
 h_{FE} = 1000 (Min) @ I_C 20 Adc
- Monolithic Construction with Built–in Base Emitter Shunt Resistor
- Junction Temperature to $+200^{\circ}$ C

MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector-Emitter Voltage	MJ11012 MJ11015/6	V _{CEO}	60 120	Vdc
Collector-Base Voltage	MJ11012 MJ11015/6	V _{CB}	60 120	Vdc
Emitter-Base Voltage		V _{EB}	5	Vdc
Collector Current		Ι _C	30	Adc
Base Current		Ι _Β	1	Adc
Total Device Dissipation @ Derate above $25^{\circ}C$ @ T _C =		PD	200 1.15	W W/°C
Operating Storage Junction Temperature Range	1	T _J , T _{stg}	-55 to +200	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	0.87	°C/W
Maximum Lead Temperature for Sol- dering Purposes for ≤ 10 Seconds	ΤL	275	°C

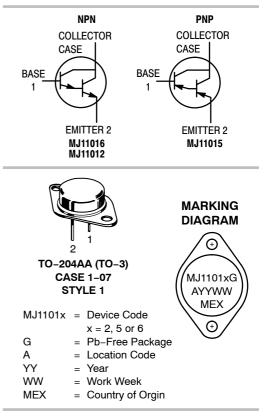
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



ON Semiconductor®

http://onsemi.com

30 AMPERE DARLINGTON POWER TRANSISTORS COMPLEMENTARY SILICON 60 – 120 VOLTS, 200 WATTS



ORDERING INFORMATION

Device	Package	Shipping
MJ11012	TO-3	100 Units/Tray
MJ11012G	TO-3 (Pb-Free)	100 Units/Tray
MJ11015	TO-3	100 Units/Tray
MJ11015G	TO-3 (Pb-Free)	100 Units/Tray
MJ11016	TO-3	100 Units/Tray
MJ11016G	TO-3 (Pb-Free)	100 Units/Tray

Preferred devices are recommended choices for future use and best overall value.

MJ11015 (PNP); MJ11012, MJ11016 (NPN)

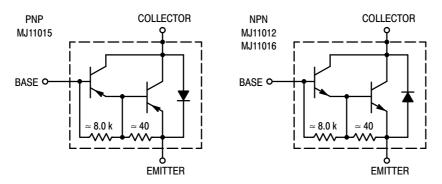
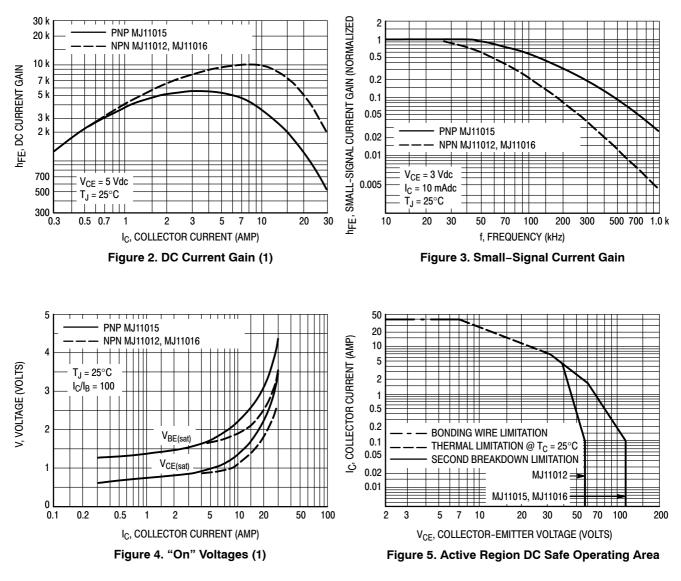


Figure 1. Darlington Circuit Schematic

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted.)

Characteristics		Symbol	Min	Max	Unit
OFF CHARACTERISTICS					-
Collector-Emitter Breakdown Voltage(1) (I _C = 100 mAdc, I _B = 0)	MJ11012 MJ11015, MJ11016	V _{(BR)CEO}	60 120		Vdc
$ Collector-Emitter Leakage Current \\ (V_{CE} = 60 Vdc, R_{BE} = 1k ohm) \\ (V_{CE} = 120 Vdc, R_{BE} = 1k ohm) \\ (V_{CE} = 60 Vdc, R_{BE} = 1k ohm, T_C = 150^\circ C) \\ (V_{CE} = 120 Vdc, R_{BE} = 1k ohm, T_C = 150^\circ C) $	MJ11012 MJ11015, MJ11016 MJ11012 MJ11015, MJ11016	I _{CER}	- - - -	1 1 5 5	mAdc
Emitter Cutoff Current ($V_{BE} = 5 \text{ Vdc}, I_C = 0$)		I _{EBO}	-	5	mAdc
Collector-Emitter Leakage Current $(V_{CE} = 50 \text{ Vdc}, I_B = 0)$		I _{CEO}	-	1	mAdc
ON CHARACTERISTICS(1)					
DC Current Gain ($I_C = 20 \text{ Adc}, V_{CE} = 5 \text{ Vdc}$) ($I_C = 30 \text{ Adc}, V_{CE} = 5 \text{ Vdc}$)		h _{FE}	1000 200		-
Collector-Emitter Saturation Voltage ($I_C = 20$ Adc, $I_B = 200$ mAdc) ($I_C = 30$ Adc, $I_B = 300$ mAdc)		V _{CE(sat)}		3 4	Vdc
Base-Emitter Saturation Voltage $(I_C = 20 \text{ A}, I_B = 200 \text{ mAdc})$ $(I_C = 30 \text{ A}, I_B = 300 \text{ mAdc})$		V _{BE(sat)}		3.5 5	Vdc
DYNAMIC CHARACTERISTICS		•		•	•
Current–Gain Bandwidth Product $(I_C = 10 \text{ A}, V_{CE} = 3 \text{ Vdc}, f = 1 \text{ MHz})$		h _{fe}	4	_	MHz

(1) Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.



MJ11015 (PNP); MJ11012, MJ11016 (NPN)

There are two limitations on the power handling ability of a transistor average junction temperature and secondary breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operations e.g., the transistor must not be subjected to greater dissipation than the curves indicate.

At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by secondary breakdown.

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS



DIMENSIONS			
SCALE 1:1	TO–204 (TO–3) CASE 1–07 ISSUE Z)	DATE 05/18/1988
$ \begin{array}{c} $	$ \begin{array}{c} $	NOTES: 1. DIMENSIONING AND TC Y14.5M, 1982. 2. CONTROLLING DIMENS 3. ALL RULES AND NOTES REFERENCED TO-204A MIN MAX A 1.550 REF B 1.050 C 0.250 0.335 D 0.038 0.043 E 0.055 0.070 G 0.430 BSC H 0.215 BSC K 0.440 0.480 L 0.665 BSC N 0.830 Q 0.151 0.165 U 1.187 BSC V 0.131 0.188	ION: INCH.
STYLE 1: PIN 1. BASE 2. EMITTER CASE: COLLECTOR STYLE 6: PIN 1. GATE 2. EMITTER CASE: COLLECTOR	STYLE 2: STYLE 3: PIN 1. BASE PIN 1. GATE 2. COLLECTOR 2. SOURCE CASE: EMITTER CASE: DRAIN STYLE 7: STYLE 8: PIN 1. ANODE PIN 1. CATHODE #1 2. OPEN 2. CATHODE #2 CASE: CATHODE CASE: ANODE	STYLE 4: STYLE 5: PIN 1. GROUND 2. INPUT CASE: OUTPUT STYLE 9: PIN 1. ANODE #1 2. ANODE #2 CASE: CATHODE	E AL TRIP/DELAY

ON Semiconductor and **W** are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com

ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at <u>www.onsemi.com/support/sales</u>